

Practitioner's Docket No.: 811_107

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: Makoto IWAI, Katsuhiro IMAI and Minoru IMAEDA

Serial No.: 10/594,846 Art Unit: 1792

Dated Filed: November 8, 2006 Examiner: G. Nagesh Rao

Confirmation No.: 3664

For: GALLIUM NITRIDE SINGLE CRYSTAL GROWING METHOD AND
GALLIUM NITRIDE SINGLE CRYSTAL

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

AMENDMENT AFTER NON-FINAL REJECTION

Sir:

In response to the Office Action mailed February 25, 2010, please amend the above-identified application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 4 of this paper.